COMPLIANT

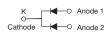
HALOGEN FREE



Vishay General Semiconductor

# High Current Density Surface Mount Schottky Barrier Rectifiers

# eSMP® Series K SMPC (TO-277A)



| PRIMARY CHARACTERISTICS |                |  |  |  |  |
|-------------------------|----------------|--|--|--|--|
| I <sub>F(AV)</sub>      | 2 x 5.0 A      |  |  |  |  |
| $V_{RRM}$               | 30 V, 40 V     |  |  |  |  |
| I <sub>FSM</sub>        | 200 A          |  |  |  |  |
| E <sub>AS</sub>         | 20 mJ          |  |  |  |  |
| $V_F$ at $I_F = 5$ A    | 0.37 V         |  |  |  |  |
| T <sub>J</sub> max.     | 150 °C         |  |  |  |  |
| Package                 | SMPC (TO-277A) |  |  |  |  |
| Circuit configuration   | Single         |  |  |  |  |

#### **FEATURES**

- Very low profile typical height of 1.1 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency
- Low thermal resistance
- Meets MSL level 1, per J-STD-020
- AEC-Q101 qualified available
  - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling diodes, DC/DC converters, and polarity protection application.

#### **MECHANICAL DATA**

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Base P/NHM3\_X - halogen-free, RoHS-compliant and

AEC-Q101 qualified

("\_X" denotes revision code e.g. A, B,....)

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

| <b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)            |              |                                   |             |         |      |
|---|--------------|-----------------------------------|-------------|---------|------|
| PARAMETER   |              | SYMBOL                            | SS10P3C     | SS10P4C | UNIT |
| Device marking code   |              |                                   | S103C       | S104C   |      |
| Maximum repetitive peak reverse voltage   |              | V <sub>RRM</sub>                  | 30          | 40      | V    |
| Maximum average forward rectified current (fig. 1)                                | total device |                                   | 10          |         | Α    |
|   | per diode    | I <sub>F(AV)</sub>                | 5.0         |         |      |
| Peak forward surge current 10 ms single half sine-wave superimposed on rated load |              | I <sub>FSM</sub>                  | 200         |         | А    |
| Non-repetitive avalanche energy at 25 °C, I <sub>AS</sub> = 2 A per diode         |              | E <sub>AS</sub>                   | 20          |         | mJ   |
| Operating junction and storage temperature range                                  |              | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 |         | °C   |



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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted) |                        |                         |                               |      |      |      |
|---|------------------------|-------------------------|-------------------------------|------|------|------|
| PARAMETER   | TEST CONDITIONS        |                         | SYMBOL                        | TYP. | MAX. | UNIT |
| Instantaneous forward voltage per diode   | I <sub>F</sub> = 2.5 A | ——— T₁ = 25 °C I        | V <sub>F</sub> <sup>(1)</sup> | 0.40 | -    | V    |
|   | $I_F = 5.0 \text{ A}$  |                         |                               | 0.45 | 0.53 |      |
|   | I <sub>F</sub> = 2.5 A | T <sub>A</sub> = 125 °C |                               | 0.29 | -    |      |
|   | I <sub>F</sub> = 5.0 A |                         |                               | 0.37 | 0.44 |      |
| Reverse current per diode   | Rated V <sub>R</sub>   | T <sub>A</sub> = 25 °C  | I <sub>R</sub> <sup>(2)</sup> | 56   | 550  | μΑ   |
|   | nated v <sub>R</sub>   | T <sub>A</sub> = 125 °C | IR (=)                        | 28   | 45   | mA   |
| Typical junction capacitance per diode  | 4.0 V, 1 MHz           |                         | CJ                            | 430  | -    | pF   |

#### Notes

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise specified) |                                |                 |  |      |  |
|---|--------------------------------|-----------------|--|------|--|
| PARAMETER   | SYMBOL                         | SS10P3C SS10P4C |  | UNIT |  |
| Typical thermal resistance per diode  | $R_{\theta JA}$ <sup>(1)</sup> | 60              |  | °C/W |  |
| Typical thermal resistance per diode  | $R_{	hetaJL}$                  | 3               |  | C/VV |  |

#### Note

(1) Units mounted on recommended PCB 1 oz. pad layout

| ORDERING INFORMATION (Example) |                 |              |               |                                    |  |  |
|--------------------------------|-----------------|--------------|---------------|------------------------------------|--|--|
| PREFERRED P/N                  | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                      |  |  |
| SS10P4C-M3/86A                 | 0.10            | 86A          | 1500          | 7" diameter plastic tape and reel  |  |  |
| SS10P4C-M3/87A                 | 0.10            | 87A          | 6500          | 13" diameter plastic tape and reel |  |  |
| SS10P4CHM3_A/H <sup>(1)</sup>  | 0.10            | Н            | 1500          | 7" diameter plastic tape and reel  |  |  |
| SS10P4CHM3_A/I (1)             | 0.10            | ļ            | 6500          | 13" diameter plastic tape and reel |  |  |

#### Note

(1) AEC-Q101 qualified

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#### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

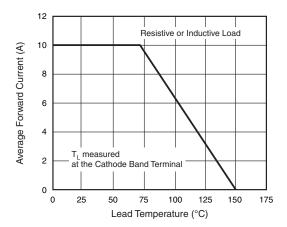


Fig. 1 - Maximum Forward Current Derating Curve

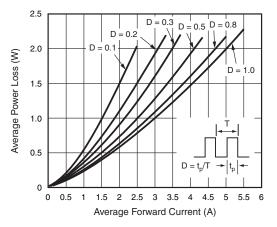


Fig. 2 - Forward Power Loss Characteristics Per Diode

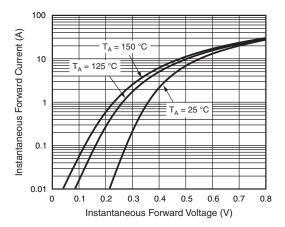


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

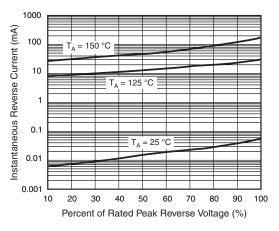


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

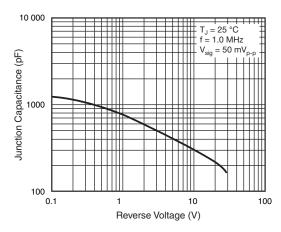


Fig. 5 - Typical Junction Capacitance Per Diode

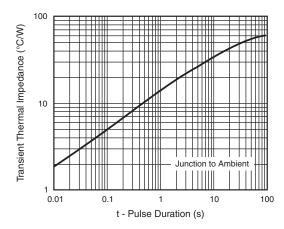
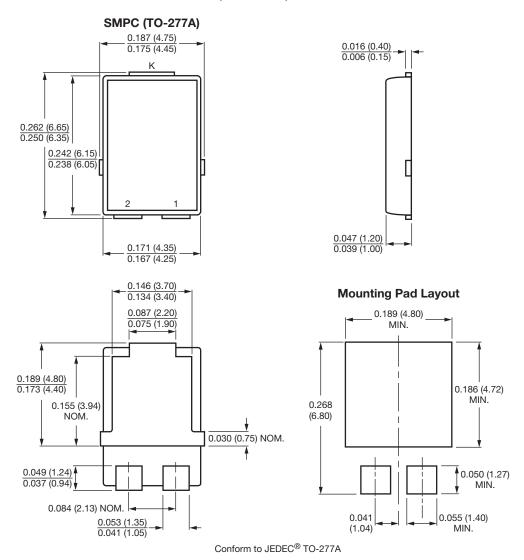


Fig. 6 - Typical Transient Thermal Impedance Per Diode



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#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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